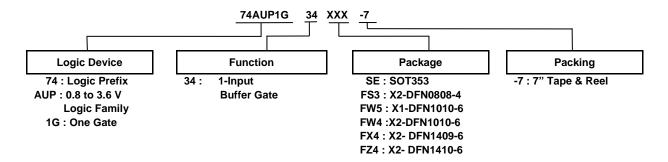


Ordering Information



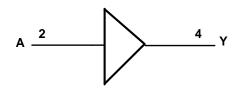
Device	Package	Package	Package	7" Tape	and Reel	
Device	Code	(Notes 4, 5)	Size	Quantity	Part Number Suffix	
74AUP1G34SE-7	SE	SOT353	2.0mm X 2.0mm X 1.1mm 0.65 mm lead pitch	3000/Tape & Reel	-7	
74AUP1G34FS3-7	FS3	X2-DFN0808-4	0.8mm X 0.8mm X 0.35mm 0.5 mm pad pitch (diamond)	5000/Tape & Reel	-7	
74AUP1G34FW5-7	FW5	X1-DFN1010-6	1.0mm X 1.0mm X 0.5mm 0.35 mm pad pitch	5000/Tape & Reel	-7	
74AUP1G34FW4-7	FW4	X2-DFN1010-6	1.0mm X 1.0mm X 0.4mm 0.35 mm pad pitch	5000/Tape & Reel	-7	
74AUP1G34FX4-7	FX4	X2-DFN1409-6 Chip scale alternative	1.4mm X 0.9mm X 0.4mm 0.5 mm pad pitch	5000/Tape & Reel	-7	
74AUP1G34FZ4-7	FZ4	X2-DFN1410-6	1.4mm X 1.0mm X 0.4mm 0.5 mm pad pitch	5000/Tape & Reel	-7	

Notes: 4. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

Pin Descriptions

Pin Name	Function				
NC	No Connection				
Α	Data Input				
GND	Ground				
Υ	Data Output				
Vcc	Supply Voltage				

Logic Diagram



Function Table

Inputs	Output
Α	Υ
Н	Н
L	L

^{5.} The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf.



Absolute Maximum Ratings (Notes 6, 7) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
V _{CC}	Supply Voltage Range	-0.5 to +4.6	V
VI	Input Voltage Range	-0.5 to +4.6	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I < 0	50	mA
I _{OK}	Output Clamp Current (V _O < 0)	50	mA
Io	Continuous Output Current (V _O = 0 to V _{CC})	±20	mA
Icc	Continuous Current Through V _{CC}	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Notes:

Recommended Operating Conditions (Note 8) (@T_A = +25°C, unless otherwise specified.)

Symbol	P	arameter	Min	Max	Unit
V _{CC}	Operating Voltage		0.8	3.6	V
VI	Input Voltage		0	3.6	V
Vo	Output Voltage		0	V _{CC}	V
		V _{CC} = 0.8V	_	-20	μA
		V _{CC} = 1.1V	_	-1.1	
	High Lavel autout august	V _{CC} = 1.4V	_	-1.7	
I _{OH}	High-Level output current	V _{CC} = 1.65V	_	-1.9	mA
		V _{CC} = 2.3V	_	-3.1	
		V _{CC} = 3.0V	_	-4	
		V _{CC} = 0.8V	_	20	μA
		V _{CC} = 1.1V	_	1.1	
	Low Lovel output ourrent	V _{CC} = 1.4V	_	1.7	
l _{OL}	Low-Level output current	V _{CC} = 1.65V	_	1.9	mA
		V _{CC} = 2.3V	_	3.1	
		V _{CC} = 3.0V	_	4	
Δt/ΔV	Input Transition Rise or Fall Rate	V _{CC} = 0.8V to 3.6V	_	200	ns/V
T _A	Operating Free-Air Temperature	•	-40	+125	°C

Note:

8. Unused inputs should be held at V_{CC} or Ground.

^{6.} Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

^{7.} Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V	T _A = -	+25°C	T _A = -40°C	C to +85°C	Unit	
Symbol	Parameter	rest Conditions	V _{CC}	Min	Max	Min	Max	Unit	
		_	0.8V to 1.65V	0.80 X V _{CC}	_	0.80 X V _{CC}	_		
V _{IH}	High-Level Input	_	1.65V to 1.95V	0.65 X V _{CC}	_	0.65 X V _{CC}	_	V	
VIH	Voltage	_	2.3V to 2.7V	1.6	_	1.6	_	V	
		_	3.0V to 3.6V	2.0	_	2.0	_		
		_	0.8V to 1.65V	_	0.30 X V _{CC}	1	0.30 X V _{CC}		
V _{IL}	Low-Level Input	_	1.65V to 1.95V	_	0.35 X V _{CC}	_	0.35 X V _{CC}	V	
V IL	Voltage		2.3V to 2.7V	_	0.7		0.7	V	
		_	3.0V to 3.6V	_	0.9		0.9		
		$I_{OH} = -20\mu A$	0.8V to 3.6V	V _{CC} – 0.1	_	V _{CC} – 0.1	_		
		I _{OH} = -1.1mA	1.1V	0.75 X V _{CC}	_	0.7 X V _{CC}	_		
		I _{OH} = -1.7mA	1.4V	1.11	_	1.03	_		
.,	High-Level	I _{OH} = -1.9mA	1.65V	1.32	_	1.3	_	.,	
VoH Output Voltage	I _{OH} = -2.3mA	0.01/	2.05	_	1.97	_	V		
		I _{OH} = -3.1mA	2.3V	1.9	_	1.85	_		
		I _{OH} = -2.7mA	2) /	2.72	_	2.67	_		
		I _{OH} = -4mA	3V	2.6	_	2.55	_		
		I _{OL} = 20μA	0.8V to 3.6V	_	0.1		0.1		
		I _{OL} = 1.1mA	1.1V	_	0.3 X V _{CC}		0.3 X V _{CC}		
		I _{OL} = 1.7mA	1.4V	_	0.31	_	0.37		
.,	Low-Level	I _{OL} = 1.9mA	1.65V	_	0.31	_	0.35	.,	
V_{OL}	Output Voltage	I _{OL} = 2.3mA	2.017	_	0.31	_	0.33	V	
		I _{OL} = 3.1mA	2.3V	_	0.44	_	0.45		
		$I_{OL} = 2.7 \text{mA}$	2)./	_	0.31	_	0.33		
		I _{OL} = 4mA	3V	_	0.44	_	0.45		
lı	Input Current	A or B Input V _I = GND to 3.6V	0 to 3.6V	_	±0.1	_	±0.5	μА	
I _{OFF}	Power Down Leakage Current	V_I or $V_O = 0V$ to 3.6V	0	_	0.2	_	0.6	μΑ	
ΔI_{OFF}	Delta Power Down Leakage Current	V_I or $V_O = 0V$ to 3.6V	0 to 0.2V	_	0.2	_	0.6	μΑ	
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	0.8V to 3.6V	_	0.5	_	0.9	μΑ	
Δlcc	Additional Supply Current	Input at V _{CC} -0.6	3.3V	_	40	_	50	μΑ	



Electrical Characteristics (cont.) (@T_A = +25°C, unless otherwise specified.)

0	D	To all O and distance	.,	T _A = -40°C	to +125°C	1114
Symbol	Parameter	Test Conditions	V _{CC}	Min	Max	Unit
		_	0.8V to 1.65V	0.80 X V _{CC}	_	
\/	High-Level Input	_	1.65V to 1.95V	0.70 X V _{CC}	_	V
V _{IH}	Voltage	_	2.3V to 2.7V	1.6	_	v
		_	3.0V to 3.6V	2.0	_	
		_	0.8V to 1.65V	_	0.25 X V _{CC}	
V _{IL}	Low-Level Input	_	1.65V to 1.95V	_	0.30 X V _{CC}	V
V IL	Voltage	_	2.3V to 2.7V	_	0.7	J
		_	3.0V to 3.6V	_	0.9	
		$I_{OH} = -20\mu A$	0.8V to 3.6V	V _{CC} – 0.11	_	
		I _{OH} = -1.1mA	1.1V	0.6 X V _{CC}	_	
		I _{OH} = -1.7mA	1.4V	0.93	_	
	High-Level	I _{OH} = -1.9mA	1.65V	1.17	_	7 , 1
Voн	V _{OH} Output Voltage	I _{OH} = -2.3mA	0.014	1.77	_	V
		I _{OH} = -3.1mA	2.3V	1.67	_	
		I _{OH} = -2.7mA	21.6	2.40	_	
		I _{OH} = -4mA	3V	2.30	_	
		I _{OL} = 20μA	0.8V to 3.6V	_	0.11	
		I _{OL} = 1.1mA	1.1V	_	0.33 X V _{CC}	1
		I _{OL} = 1.7mA	1.4V	_	0.41	1
	Low-Level	I _{OL} = 1.9mA	1.65V	_	0.39	1
V _{OL}	Output Voltage	I _{OL} = 2.3mA		_	0.36	- V
		I _{OL} = 3.1mA	2.3V	_	0.50	
		I _{OL} = 2.7mA		_	0.36	
		I _{OL} = 4mA	3V	_	0.50	1
II	Input Current	A or B Input V _I = GND to 3.6V	0 to 3.6V	_	±0.75	μA
I _{OFF}	Power Down Leakage Current	V_I or $V_O = 0$ to 3.6V	0	_	±3.5	μА
Δl _{OFF}	Delta Power Down Leakage Current	V_{I} or $V_{O} = 0$ to 3.6V	0 to 0.2V	_	±2.5	μА
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	0.8V to 3.6V	_	3.0	μA
ΔI _{CC}	Additional Supply Current	Input at V _{CC} -0.6V Other inputs at V _{CC} or GND	3.3V	_	75	μА



Switching Characteristics

C_L=5pF see Figure 1

Parameter	From Input	To Output	V	T _A = +25°C			$T_A = -40$ °C to +85°C		T _A = -40°C to +125°C		Unit
Faranietei			Vcc	Min	Тур	Max	Min	Max	Min	Max	Oilit
			V8.0	_	15.0	_	_	_	_	_	
		.,	1.2V ± 0.1V	2.6	4.7	9.2	2.0	10.0	2.0	11.0	
	A or B		1.5V ± 0.1V	2.1	3.4	5.7	1.6	6.5	1.6	7.2	
t _{pd}	AUID	ī	1.8V ± 0.15V	1.8	2.9	4.5	1.4	5.2	1.4	5.8	ns
			2.5V ± 0.2V	1.5	2.3	3.5	1.2	4.2	1.2	4.6	
			$3.3V \pm 0.3V$	1.0	2.1	3.2	1.0	3.8	1.0	4.2	

C_L=10pF see Figure 1

Parameter	From Input	To Output	V	T _A = +25°C			T _A = -40°C to +85°C		T _A = -40°C to +125°C		Unit
Faranietei			V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Oilit
			V8.0	_	18.4	_	_	_	_	_	
	A or B	Y	1.2V ± 0.1V	3.2	5.6	10.9	2.3	11.8	2.3	13.1	- ns
			1.5V ± 0.1V	2.6	4.1	6.7	1.9	7.7	1.9	8.5	
t _{pd}	AUID		1.8V ± 0.15V	2.3	3.4	5.3	1.7	6.2	1.7	6.9	
			2.5V ± 0.2V	2.0	2.9	4.2	1.5	5.0	1.5	5.5	
			3.3V ± 0.3V	1.4	2.6	3.8	1.4	4.6	1.4	5.1	

C_L=15pF see Figure 1

Parameter	From Input	To Output	V	-	Γ _A = +25°C	;	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$		Unit
			Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit
			V8.0	_	21.9	_	_	_	_	_	
		Y	1.2V ± 0.1V	3.6	6.4	12.6	2.6	13.8	2.6	15.2	
	Λ or D		1.5V ± 0.1V	3.0	4.6	7.6	2.2	8.9	2.2	9.8	
t _{pd}	A or B		1.8V ± 0.15V	2.6	3.9	6.0	2.0	7.2	2.0	7.9	ns
			2.5V ± 0.2V	2.3	3.3	4.8	1.8	5.7	1.8	6.3	
			$3.3V \pm 0.3V$	1.6	3.1	4.2	1.6	5.0	1.6	5.5	

C_L=30pF see Figure 1

Parameter	From Input	To Output	.,		$T_A = +25^{\circ}C$			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	
i arameter			V _{CC}	Min	Тур	Min	Min	Max	Min	Max	Unit
			V8.0	_	32.1	_	_	_	_	_	
		.,	1.2V ± 0.1V	4.8	8.9	16.3	3.6	18.9	3.6	20.8	
	Λ or D		1.5V ± 0.1V	4	6.2	10.3	3.4	12.2	3.4	13.4	
t _{pd}	A or B	ř	1.8V ± 0.15V	3.6	5.2	8.1	3.2	9.8	3.2	10.8	ns
			2.5V ± 0.2V	3	4.4	6.4	2.7	7.7	2.7	8.5	
			$3.3V \pm 0.3V$	1.9	4.2	5.6	1.9	6.5	1.9	7.2	



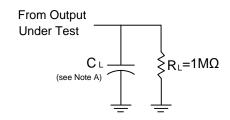
Operating and Package Characteristics (@T_A = +25°C, unless otherwise specified.)

	Parameter	Test Conditio	ns	V _{CC}	Тур	Unit
				0.8V	6.7	
				1.2V ± 0.1V	6.6	
	Power Dissipation	sipation f = 1MHz		1.5V ± 0.1V	6.5	
C_{pd}	Capacitance	No Loa	d	1.8V ± 0.15V	6.5	pF
				2.5V ± 0.2V	6.4	
				3.3V ± 0.3V	6.3	
Ci	Input Capacitance	$V_i = V_{CC}$ or	GND	0V or 3.3V	1.5	pF
		SOT353		_	371	
		X2-DFN0808-4	(Nata 0)	_	430	
	Thermal Resistance	X1-DFN1010-6		_	435	20044
θ_{JA}	Junction-to-Ambient	X2-DFN1010-6	(Note 9)	_	445	°C/W
		X2-DFN1409-6		_	470	
		X2-DFN1410-6		_	460	
		SOT353		_	143	
		X2-DFN0808-4		_	240	
	Thermal Resistance	X1-DFN1010-6	() - 1 - 0	_	250	20044
θ_{JC}	Junction-to-Case	X2-DFN1010-6	(Note 9	_	250	°C/W
		X2-DFN1409-6		_	275	
		X2-DFN1410-6		_	265	

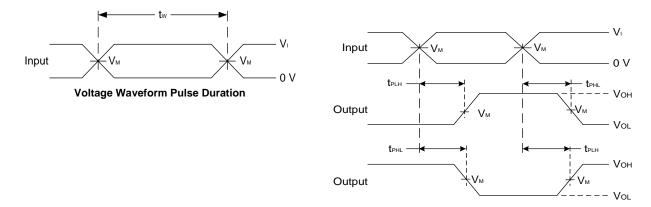
Note: 9. Test condition for each of the 6 package types: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



Parameter Measurement Information



Voc	Inputs		V	
Vcc	VI	t _r /t _f	V _M	CL
0.8V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
1.2V±0.1V	Vcc	≤3ns	V _{CC} /2	5, 10, 15, 30pF
1.5V±0.1V	Vcc	≤3ns	V _{CC} /2	5, 10, 15, 30pF
1.8V ±0.15V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
2.5V±0.2V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
3.3V±0.3V	Vcc	≤3ns	V _{CC} /2	5, 10, 15, 30pF



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Figure 1 Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

B. All pulses are supplied at pulse repetition rate ≤ 10MHz.

- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD}.



Marking Information

(1) SOT353

(Top View)

4 XX Y WX2 3

XX: Identification code

Y: Year 0~9

<u>W</u>: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents 52 and 53 week

 \underline{X} : $A^{\sim}Z$: Internal code

Part Number	Package	Identification Code
74AUP1G34SE	SOT353	XV

(2) X2-DFN0808-4, X1-DFN1010-6, X2-DFN1010-6, X2-DFN1409-6 and X2-DFN1410-6

(Top View)

<u>XX</u> $\underline{Y}\underline{W}\underline{X}$ XX: Identification Code

<u>Y</u> : Year : 0~9

<u>W</u>: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents 52 and 53 week

X: A~Z: Internal code

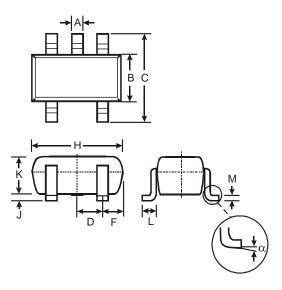
Part Number	Package	Identification Code
74AUP1G34FS3	X2-DFN0808-4	YV
74AUP1G34FW5	X1-DFN1010-6	QV
74AUP1G34FW4	X2-DFN1010-6	XV
74AUP1G34FX4	X2-DFN1409-6	НМ
74AUP1G34FZ4	X2-DFN1410-6	XV



Package Outline Dimensions (All dimensions in mm.)

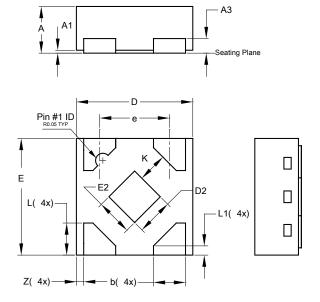
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

(1) SOT353



SOT353			
Dim	Min	Max	Тур
Α	0.10	0.30	0.25
В	1.15	1.35	1.30
С	2.00	2.20	2.10
D	0	.65 Typ	
F	0.40	0.45	0.425
Н	1.80	2.20	2.15
J	0	0.10	0.05
K	0.90	1.00	1.00
L	0.25	0.40	0.30
M	0.10	0.22	0.11
α	0°	8°	-
All Dimensions in mm			

(2) X2-DFN0808-4



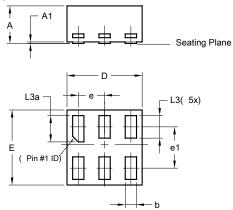
X2-DFN0808-4			
Dim	Min	Max	Тур
Α	0.25	0.35	0.30
A1	0	0.04	0.02
A3	-	-	0.13
b	0.17	0.27	0.22
D	0.75	0.85	0.80
D2	0.15	0.35	0.25
Е	0.75	0.85	0.80
E2	0.15	0.35	0.25
е	-	-	0.48
K	0.20	-	-
١	0.17	0.27	0.22
L1	0.02	0.12	0.07
Z	-	-	0.05
All Dimensions in mm			



Package Outline Dimensions (cont.) (All dimensions in mm.)

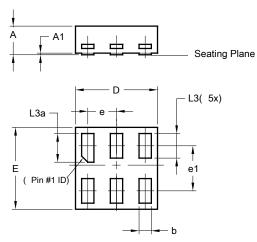
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

(3) Package Type: X1-DFN1010-6



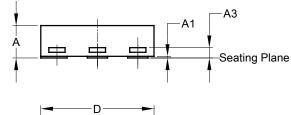
	X1-DFN1010-6			
Dim	Min	Max	Тур	
Α	-	0.50	0.39	
A1	-	0.04	-	
b	0.12	0.20	0.15	
D	0.95	1.050	1.00	
Е	0.95	1.050	1.00	
е	0.55 BSC			
e1	0.35 BSC			
L3	0.27	0.30	0.30	
L3a	0.32	0.40	0.35	
All Dimensions in mm				

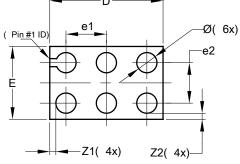
(4) X2-DFN1010-6



X2-DFN1010-6			
Dim	Min	Max	Тур
Α	-	0.35	-
A1	-	0.04	-
b	0.12	0.20	0.15
D	0.95	1.050	1.00
Е	0.95	1.050	1.00
е	0.55 BSC		
e1	0.35 BSC		
L3	0.27	0.30	0.30
L3a	0.32	0.40	0.35
All Dimensions in mm			

(5) X2-DFN1409-6





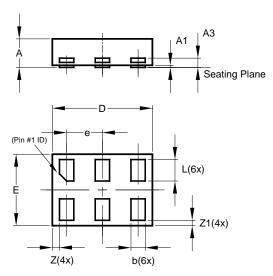
X2-DFN1409-6			
Dim	Min	Max	Тур
Α	-	0.40	0.39
A1	0	0.05	0.02
А3	-	-	0.13
Ø	0.20	0.30	0.25
D	1.35	1.45	1.40
Е	0.85	0.95	0.90
e1	-	-	0.50
e2	-	-	0.50
Z 1	-	-	0.075
Z2	-	-	0.075
All Dimensions in mm			



Package Outline Dimensions (cont.) (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

(6) X2-DFN1410-6

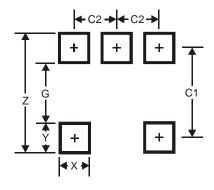


X2-DFN1410-6			
Dim	Min	Max	Тур
Α		0.40	0.39
A1	0.00	0.05	0.02
A3			0.13
b	0.15	0.25	0.20
D	1.35	1.45	1.40
Е	0.95	1.05	1.00
е			0.50
L	0.25	0.35	0.30
Z	_	_	0.10
Z 1	0.045	0.105	0.075
All Dimensions in mm			

Suggested Pad Layout

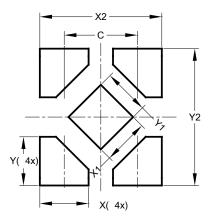
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version

(1) SOT353



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Y	0.6
C1	1.9
C2	0.65

(2) X2-DFN0808-4



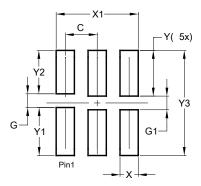
Dimensions	Value (in mm)
С	0.480
Х	0.320
X1	0.300
X2	0.800
Y	0.320
Y1	0.300
Y2	0.900



Suggested Pad Layout

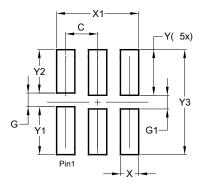
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version

(3) X1-DFN1010-6



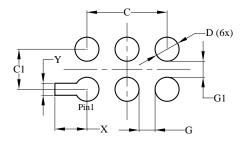
Dimensions	Value (in mm)
С	0.350
G	0.150
G1	0.150
Х	0.200
X1	0.900
Υ	0.500
Y1	0.525
Y2	0.475
Y3	1.150

(4) X2-DFN1010-6



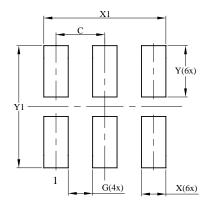
Dimensions	Value (in mm)
С	0.350
G	0.150
G1	0.150
Х	0.200
X1	0.900
Υ	0.500
Y1	0.525
Y2	0.475
Y3	1.150

(5) X2-DFN1409-6



Dimensions	Value (in mm)
С	1.000
C1	0.500
D	0.300
G	0.200
G1	0.200
Х	0.400
Y	0.150

(6) X2-DFN1410-6



Dimensions	Value (in mm)
С	0.500
G	0.250
X	0.250
X1	1.250
Y	0.525
Y1	1.250



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